

TPS923621/2 30V Synchronous Boost LED Driver with Ultra-low Shutdown Current and 0.1%-ratio PWM Controlled Analog Dimming

1 Features

- 2.5V to 5.5V input voltage
- 1.2V I/O Compatible for ADIM pin
- Integrated 280mΩ/600mΩ LS/HS switch FETs
- Up to 95% efficiency
- 130nA ultra-low shutdown current
- High-accuracy PWM controlled analog dimming down to 0.1% dimming ratio
- Drives LED string up to 30V
- Switch current limit
 - 1.8A for TPS923621
 - 2.25A for TPS923622
- FCCM with 1.1MHz switching frequency options
- 200mV feedback voltage
- Internal compensation
- Protection Features
 - Over-voltage protection
 - Over-current protection
 - Under-voltage lockout protection
 - Thermal shutdown

2 Applications

- LCD back lighting
 - Smartphone
 - Thermostat
 - HMI panel
 - GPS personal navigation device
 - Dashboard camera
- General illumination
 - IP network camera
 - Video doorbell
 - Vacuum robot

3 Description

The TPS923621/2 is a synchronous boost LED driver that integrates both low-side and high-side switch FETs. It features an ultra-low 130nA shutdown current. The TPS923621/2 can drive single or parallel LED strings for LCD back lighting and general illumination.

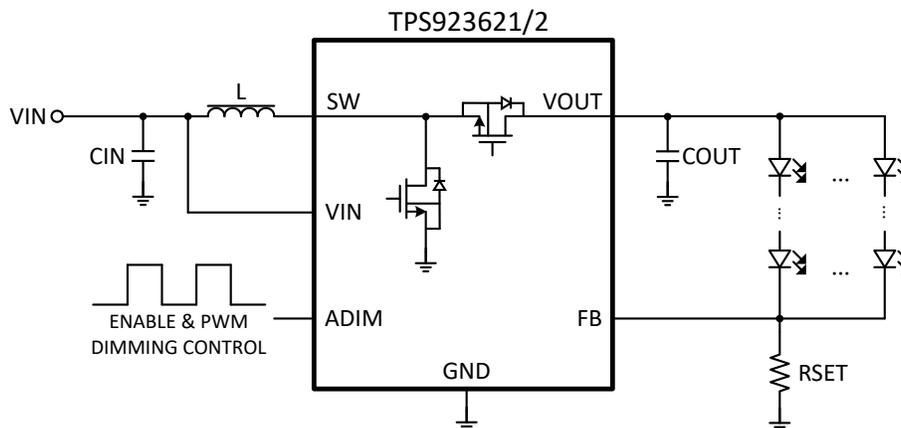
The feedback voltage is regulated to 200mV and the output current is set by an external sensor resistor, R_{SET} , as shown in the [Simplified Schematic](#). During operation, a PWM signal applied to ADIM pin adjusts the feedback voltage proportionally to the PWM duty cycle, enabling precise analog dimming. The TPS923621/2 supports PWM controlled analog dimming with ratio as low as 0.1%, along with FCCM operation, avoiding audible noises at the output since current modulation remains purely analog.

The TPS923621/2 integrates over-voltage protection that disables the power stage to prevent the output voltage from exceeding the absolute maximum voltage rating during LED open conditions. The TPS923621/2 also provides over-current protection, under-voltage lockout protection and thermal shutdown protection.

Device Information

PART NUMBER ⁽¹⁾	PACKAGE	PACKAGE SIZE (NOM)
TPS923621	SOT563 (6)	1.60mm × 1.60mm
TPS923622	WSON (6)	2.00mm × 2.00mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.



Simplified Schematic



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4 Device Comparison Table

PART NUMBER	MATERIAL	CURRENT LIMIT	PACKAGE
TPS923621	TPS923621DRLR	1.8A	SOT563-6
TPS923622	TPS923622DRVR	2.25A	WSON-6

5 Pin Configuration and Functions

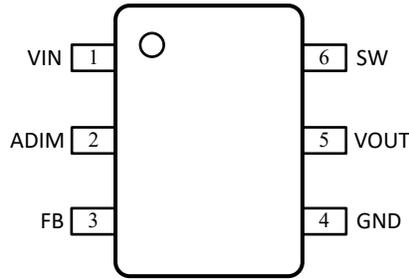


Figure 5-1. SOT563-6 DRL Package (Top View)

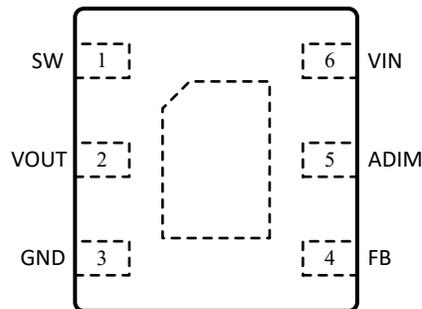


Figure 5-2. WSON-6 DRV Package (Top View)

Table 5-1. Pin Functions

NAME	PIN		TYPE ⁽¹⁾	DESCRIPTION
	DRL	DRV		
VIN	1	6	I	Supply input pin.
ADIM	2	5	I	Enable, shutdown and PWM controlled analog dimming input pin. FB voltage is proportional to the input PWM duty cycle.
FB	3	4	I	Feedback pin for output current. Connect the sense resistor from FB to GND.
GND	4	3	G	Ground.
VOUT	5	2	P	Output pin.
SW	6	1	P	Switch pin of the converter. It is connected to the drain of the internal low-side switch FET and source of the internal high-side switch FET.

(1) I = Input, O = Output, P = Power, G = Ground

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Voltage range at terminals ⁽²⁾	V _{IN}	-0.3	6	V
	SW	-1	32	V
	SW (transient <10ns)	-1	38	V
	V _{OUT}	-0.3	32	V
	FB, PWM	-0.3	5.5	V
T _J ⁽³⁾	Operating junction temperature	-40	150	°C
T _{stg}	Storage temperature	-65	150	°C

- (1) Operation outside the Absolute Maximum Ratings may cause permanent device damage. Absolute Maximum Ratings do not imply functional operation of the device at these or any other conditions beyond those listed under Recommended Operating Conditions. If used outside the Recommended Operating Conditions but within the Absolute Maximum Ratings, the device may not be fully functional, and this may affect device reliability, functionality, performance, and shorten the device lifetime.
- (2) All voltage values are with respect to network ground terminal.
- (3) High junction temperatures degrade operating lifetime. Operating lifetime is de-rated for junction temperatures greater than 125°C.

6.2 ESD Ratings

			VALUE	UNIT
V _(ESD) ⁽¹⁾	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽²⁾	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽³⁾	±500	

- (1) Electrostatic discharge (ESD) to measure device sensitivity and immunity to damage caused by assembly line electrostatic discharges into the device.
- (2) Level listed above is the passing level per ANSI, ESDA, and JEDEC JS-001. JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.
- (3) Level listed above is the passing level per EIA-JEDEC JESD22-C101. JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V _{IN}	Input voltage	2.5		5.5	V
V _{OUT}	Output voltage	5		30	V
C _{IN}	Input capacitance, effective value	1			µF
C _{OUT}	Output capacitance, effective value	1			µF
T _J	Operating junction temperature	-40		125	°C

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		SOT563 DRL		WSO5N DRV		UNIT
		6 PINS		6 PINS		
		Standard	EVM	Standard	EVM	
R _{θJA}	Junction-to-ambient thermal resistance	142.7	87.85	93.71	81.69	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	72.6	NA	108.56	64.83	°C/W
R _{θJB}	Junction-to-board thermal resistance	31.6	NA	54.15	55.55	°C/W
ψ _{JT}	Junction-to-top characterization parameter	2.3	14.53	11.58	24.91	°C/W

THERMAL METRIC ⁽¹⁾		SOT563 DRL		WSO6 DRV		UNIT
		6 PINS		6 PINS		
		Standard	EVM	Standard	EVM	
ψ_{JB}	Junction-to-board characterization parameter	30.5	57.6	54.27	56.13	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics

$T_J = -40$ to 125°C , $V_{IN} = 3.6$ V. Typical values are at $T_J = 25^\circ\text{C}$, (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER SUPPLY						
V_{IN}	Input voltage range		2.5		5.5	V
V_{IN_UVLO}	VIN under voltage lockout threshold	V_{IN} rising		2.3	2.49	V
		V_{IN} falling	2.05	2.17		V
I_Q	Quiescent current into V_{IN} pin	Chip enable. No switching.		260	300	μA
I_{SD}	Shutdown current into V_{IN} pin	ADIM = 0 (IC disabled), $T_J = 25^\circ\text{C}$		0.13	0.25	μA
		ADIM = 0 (IC disabled), T_J up to 85°C		0.13	0.5	μA
CONTROL LOGIC						
V_{ADIM_H}	ADIM Logic high threshold	T_J up to 85°C	0.855			V
V_{ADIM_L}	ADIM Logic low threshold	T_J up to 85°C			0.385	V
R_{ADIM_PD}	ADIM pin internal pull down resistor			600		k Ω
t_{ADIM_EN} ⁽¹⁾	ADIM first pulse high time to enable device		40			us
t_{ADIM_SD} ⁽¹⁾	ADIM logic low time to shutdown		2.5			ms
t_{ADIM_PWM} ⁽¹⁾	ADIM minimum PWM on time for dimming		20			ns
VOLTAGE REFERENCE						
V_{FB}	PWM duty cycle 100% (TPS923621)		195	200.5	206	mV
		$T_J = 25^\circ\text{C}$	198	200.5	203	mV
	PWM duty cycle 10% (TPS923621)		14.5	20.2	25.5	mV
		$T_J = 25^\circ\text{C}$	18	20.2	22	mV
	PWM duty cycle 1% (TPS923621)	$T_J = 25^\circ\text{C}$	1.7	2.2	2.7	mV
	PWM duty cycle 0.1% (TPS923621) ⁽¹⁾	$T_J = 25^\circ\text{C}$		0.35		mV
	PWM duty cycle 100% (TPS923622)		198	203	207	mV
		$T_J = 25^\circ\text{C}$	201	203	206	mV
	PWM duty cycle 10% (TPS923622)	$T_J = 25^\circ\text{C}$	16	20.6	26	mV
PWM duty cycle 1% (TPS923622)	$T_J = 25^\circ\text{C}$	18.6	20.6	22.6	mV	
PWM duty cycle 0.1% (TPS923622) ⁽¹⁾	$T_J = 25^\circ\text{C}$	1.75	2.25	2.75	mV	
PWM duty cycle 0.1% (TPS923622) ⁽¹⁾	$T_J = 25^\circ\text{C}$		0.35		mV	
I_{FB}	FB pin bias current	$V_{FB}=200\text{mV}$			0.1	μA
SWITCH CONVERTER						
R_{DSON_LS}	Low-side switch FET on resistance (TPS923621)			280	400	m Ω
		$T_J = 25^\circ\text{C}$		280	300	m Ω
	Low-side switch FET on resistance (TPS923622)			300	420	m Ω
		$T_J = 25^\circ\text{C}$		300	320	m Ω
R_{DSON_HS}	High-side switch FET on resistance (TPS923621)			600	900	m Ω
		$T_J = 25^\circ\text{C}$		600	680	m Ω
	High-side switch FET on resistance (TPS923622)			625	925	m Ω
		$T_J = 25^\circ\text{C}$		625	705	m Ω
F_{SW} ⁽¹⁾	Switching frequency (TPS923621DRLR, TPS923622DRVR)			1.1		MHz
V_{OVP_R}	VOUT over-voltage rising threshold (TPS923621, TPS923622)		29.6	30.5	31.4	V

$T_J = -40$ to 125°C , $V_{IN} = 3.6$ V. Typical values are at $T_J = 25^\circ\text{C}$, (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{OVP_HYS}	VOUT over-voltage falling threshold			1		V
CURRENT LIMIT						
I_{LIM}	FET switching peak current limit (TPS923621)		1.6	1.8	2.1	A
	FET switching peak current limit (TPS923622)		1.95	2.25	2.6	A
$I_{LIM_START}^{(1)}$	FET switching start-up peak current			0.8		A
THERMAL SHUTDOWN						
$T_{TSD_R}^{(1)}$	Thermal shutdown rising threshold	T_J rising		170		$^\circ\text{C}$
$T_{TSD_F}^{(1)}$	Thermal shutdown falling threshold	T_J falling		150		$^\circ\text{C}$

(1) Not production tested. Guaranteed by simulation and bench test.

6.6 Typical Characteristics

At $T_A = 25^\circ\text{C}$, unless otherwise noted.

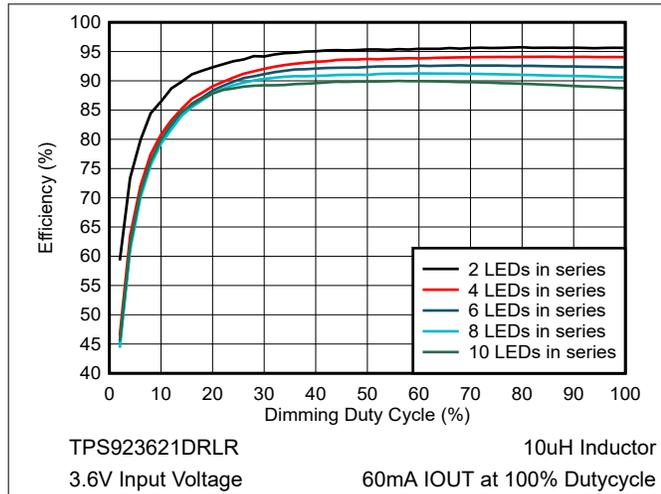


Figure 6-1. Efficiency vs Dimming Duty Cycle

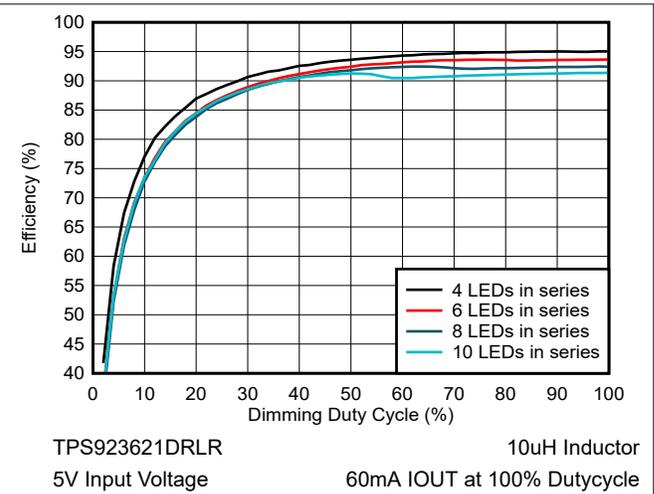


Figure 6-2. Efficiency vs Dimming Duty Cycle

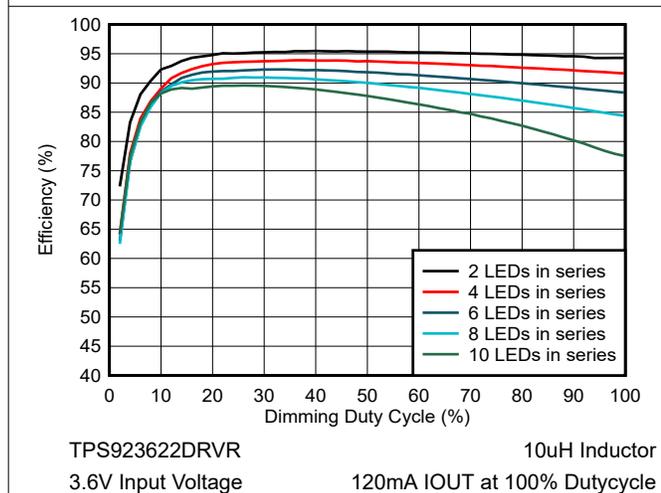


Figure 6-3. Efficiency vs Dimming Duty Cycle

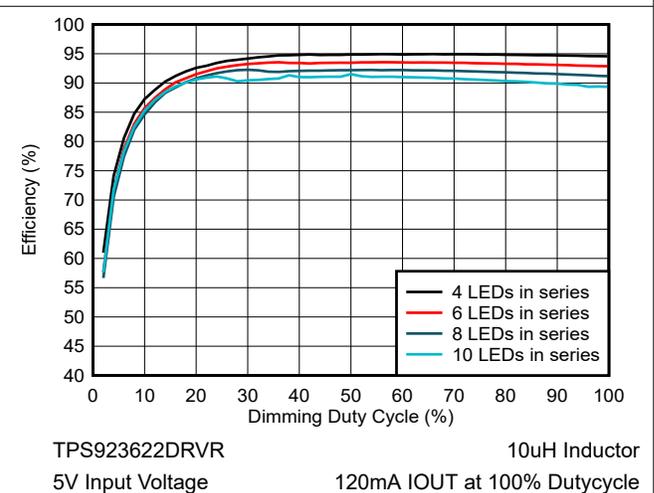
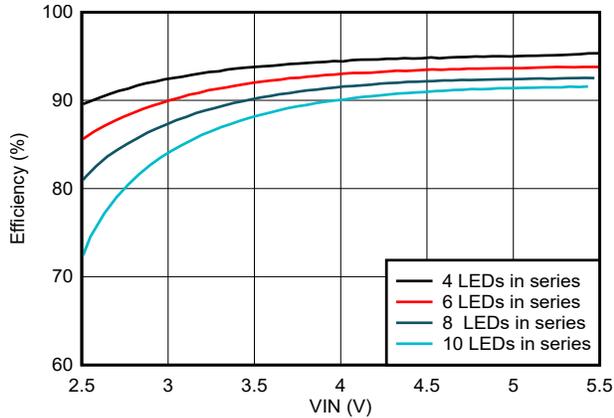
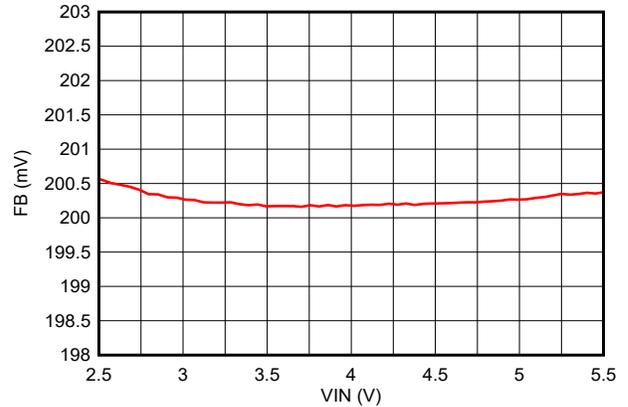


Figure 6-4. Efficiency vs Dimming Duty Cycle



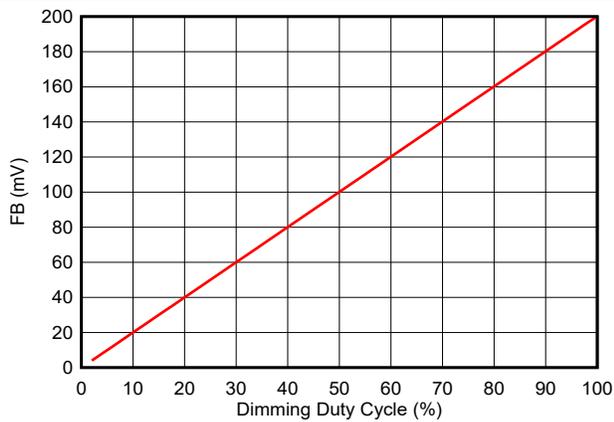
TPS923621DRLR 60mA IOUT 10uH Inductor

Figure 6-5. Efficiency vs VIN



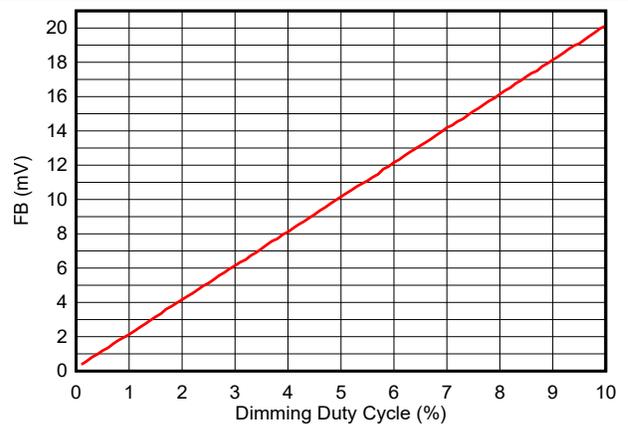
TPS923621DRLR 60mA IOUT 10uH Inductor

Figure 6-6. FB vs VIN



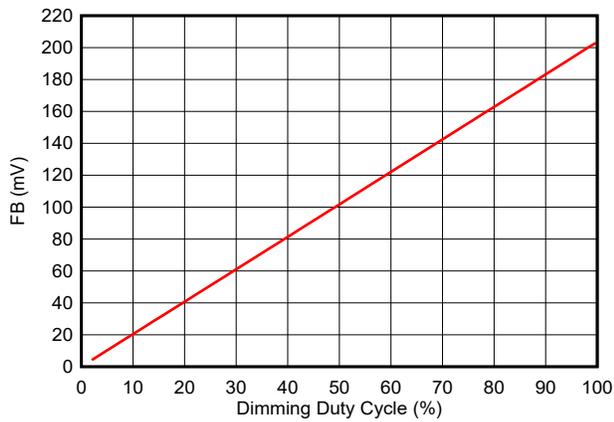
TPS923621DRLR 3.6V VIN 10uH Inductor

Figure 6-7. FB vs Dimming Duty Cycle 1%~100%



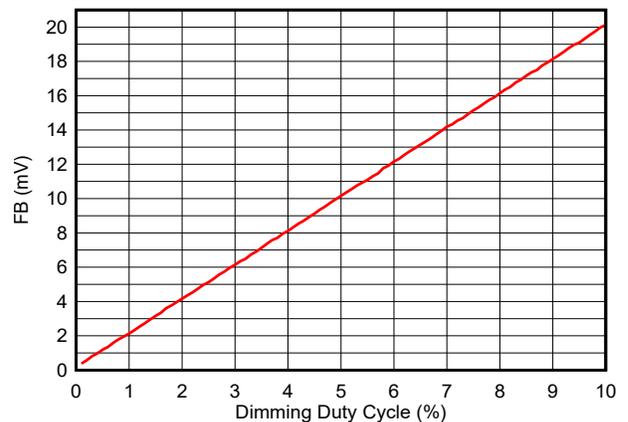
TPS923621DRLR 3.6V VIN 10uH Inductor

Figure 6-8. FB vs Dimming Duty Cycle 0.1%~10%



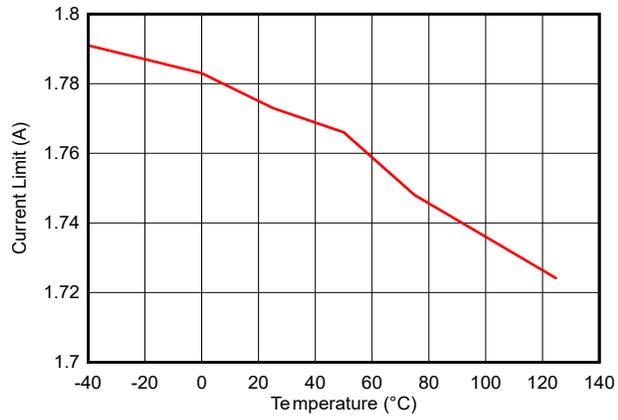
TPS923622DRVR 3.6V VIN 10uH Inductor

Figure 6-9. FB vs Dimming Duty Cycle 1%~100%



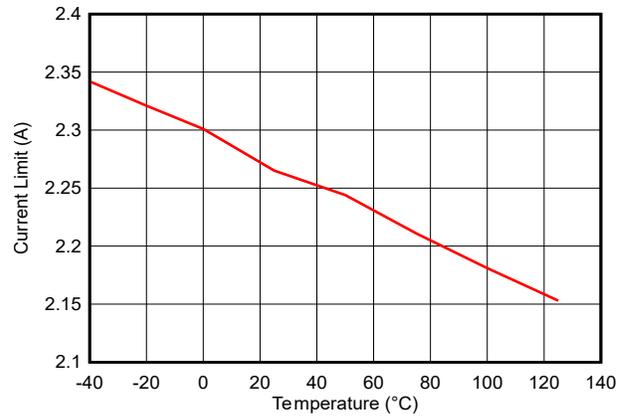
TPS923622DRVR 3.6V VIN 10uH Inductor

Figure 6-10. FB vs Dimming Duty Cycle 0.1%~10%



TPS923621DRLR 3.6V VIN 10uH Inductor

Figure 6-11. Current Limit vs Temperature



TPS923622DRVR 3.6V VIN 10uH Inductor

Figure 6-12. Current Limit vs Temperature

7 Detailed Description

7.1 Overview

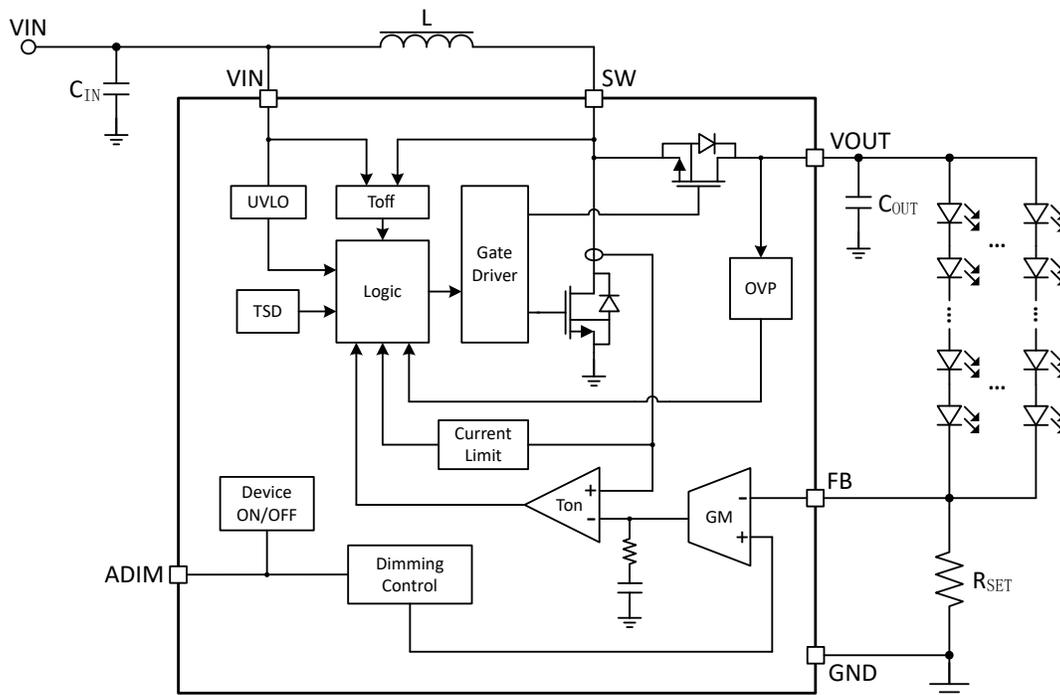
The TPS923621/2 is a high-current, high-efficiency, high-output-voltage fully-integrated synchronous boost converter in small package size. The device integrates 280mΩ low-side switch FET and 600mΩ high-side switch FET and is designed for output voltage up to 30V with a switch peak current limit of 2.25A. Its large driving capability can drive single or parallel LED strings for small to large size LCD panel back lighting or general illumination.

The TPS923621/2 operates in peak current mode (PCM) control with quasi-constant frequency. It is internally compensated for maximum flexibility and stability, which also enables a simple design. During the low-side switch FET on-time, the inductor current rises until reaching a threshold value set by the internal GM amplifier. Then, the low-side switch FET is turned off and the high-side switch FET is turned on which lets the current flow towards the output of the boost converter. The adaptive off-time varies as a function of V_{IN} and V_{OUT} , to maintain a nearly constant frequency, which provides better stability for the system over a wider range of input voltage and output voltage than conventional boost converters. The TPS923621/2 topology also has the benefits of providing very good load and line regulations, and excellent line and load transient responses.

The TPS923621/2 implements PWM controlled analog dimming by changing feedback (FB) voltage proportional to the duty cycle of PWM input signal in 0.1% to 100% range. The feedback loop regulates the FB pin to a reference voltage of 200mV for 100% PWM duty cycle, reducing the power dissipation in the current sense resistor.

The TPS923621/2 is optimized for single-cell lithium-ion battery applications, featuring an ultra-low 130nA shutdown current that extends battery life. It can support 2.5V low V_{IN} when battery near full discharge. The TPS923621/2 has both 1.1MHz version and 400KHz version switch frequency options. The 1.1MHz version supports ultra-compact surface-mount inductors and capacitors, while the 400KHz version is ideal for applications with EMI constraints near the 1.1MHz frequency band.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Enable and Start-up

The ADIM pin performs not only the dimming function, but also the enable/shutdown function. When the V_{IN} voltage is above the UVLO threshold, the TPS923621/2 can be enabled by driving the ADIM pin higher than the threshold voltage V_{ADIM_H} for a period longer than t_{ADIM_EN} .

Soft-start function is integrated into the device to avoid high inrush current spike during start-up. After the device is enabled, the GM amplifier output voltage ramps up very slowly. During this period, the switch current limit is set to I_{LIM_STRAT} . After this period, the switch current limit changes back to I_{LIM} and the FB pin voltage ramps up to reference voltage slowly. These features maintain the smooth start-up and minimize the inrush current.

7.3.2 Under-Voltage Lockout (UVLO)

The UVLO circuit prevents the device from malfunctioning at low input voltage and the battery from excessive discharge. When the input voltage, V_{IN} , falls below the UVLO falling threshold, the device is shut down, and the internal switch FETs is turned off. When the input voltage, V_{IN} , rises above the UVLO rising threshold, the device starts operating.

7.3.3 Shutdown

The TPS923621/2 enters shutdown mode when the ADIM pin voltage is logic low for more than 2.5ms. During shutdown, the input supply current for the device is only 130nA typically. Although there is still a path between the input and the LEDs through the inductor and body diode of internal high-side FET, the current of this path is neglectable since the forward voltage of the LED string added the forward voltage of internal high-side FET body diode exceeds the maximum input voltage, V_{IN} , which maintains that the LEDs remain off in shutdown and no contribution to shutdown current.

7.3.4 Boost Control Operation

The TPS923621/2 uses peak current mode (PCM) control and full internal compensation to provide high transient response performance over a wide range of operating conditions.

In the normal operation, at the beginning of each switching cycle, the low-side switch FET is turned on and the inductor current ramps up to a peak current determined by the output of the internal GM amplifier. After the peak current is reached, the current comparator trips and turns off the low-side switch FET. Then, the inductor current goes through the body diode of the high-side switch FET in a dead-time duration and the inductor current decreases. After the dead-time duration, the high-side switch FET is turned on and is not turned off until the calculated adaptive off-time is reached. The adaptive off-time varies as a function of V_{IN} and V_{OUT} , to maintain a nearly constant frequency. After the high-side switch FET is turned off, the inductor current goes through the body diode of the high-side switch FET again in another dead-time duration. After the dead-time duration, the low-side switch FET is turned on again and the switching cycle is repeated.

In light load condition, the TPS923621/2 works in forced continuous conduction mode (FCCM). During FCCM, the switching frequency is maintained at an almost constant level over the entire load range. This feature not only benefits the small output current accuracy, but also reduces output ripple and avoids audible noise caused by switching frequency drop.

7.3.5 Switching Peak Current Limit

To prevent an over-current stress, the output of the internal GM amplifier has a internal high clamp in order to set a cycle-by-cycle current limit to the inductor peak current. The low-side switch FET is turned off immediately as soon as the inductor current touches the current limit, I_{LIM} .

7.3.6 Over-Voltage Protection

The TPS923621/2 integrates over-voltage protection preventing over-voltage on the output and securing the circuits connected to the output from excessive-voltage damage in fault conditions, such as LED string open circuit.

When the voltage of VOUT pin exceeds V_{OVP_R} , the TPS923621/2 stops switching immediately until the voltage at the VOUT pin drops the hysteresis value to lower than $V_{OVP_R}-V_{OVP_HYS}$. Then, the switching restarts again. After the detection above is triggered 3 times, the TPS923621/2 enters over-voltage protection mode, in which the switching stops and does not resume switching even if the voltage at the VOUT pin falls below $V_{OVP_R}-V_{OVP_HYS}$. The TPS923621/2 remains in over-voltage protection mode until it is reset by two ways, which are shutdown and re-enabling device by the ADIM pin or triggering UVLO by the VIN pin.

7.3.7 Output Current Setting

The FB voltage is regulated to a 200mV reference voltage. The LED current is set externally using a current-sense resistor in series with the LED strings. The value of the R_{SET} (R3 on EVM) is calculated using:

$$I_{OUT} = \frac{V_{FB}}{R_{SET}} \quad (1)$$

where

- I_{LED} = total output current of LED strings
- V_{FB} = regulated voltage of FB pin
- R_{SET} = current sense resistor

The output current tolerance depends on the FB accuracy and the current sensor resistor accuracy.

R2 is optional resistor paralleled with R3 to fine tune the R_{SET} to target value, or used to balance the total power loss on R_{SET} .

7.3.8 Output Current PWM Controlled Analog Dimming

The TPS923621/2 implements PWM controlled analog dimming to adjust the brightness of LED strings during operation. Pulse width modulation (PWM) signal can be applied at ADIM pin to control the total output current as an analog value. When the voltage of the ADIM pin is constantly high, the voltage of the FB pin is regulated to the full value, 200mV typically. When the signal applied to the ADIM pin is PWM, the regulation voltage at the FB pin is reduced to the full value multiplied by PWM duty cycle, and as a result, the total output current is reduced, too. The TPS923621/2 supports such dimming method with dimming ratio down to 0.1%.

The relationship between the PWM duty cycle and FB regulation voltage is given by:

$$V_{FB} = Duty \times 200mV \quad (2)$$

where

- Duty = Duty cycle of the input PWM signal
- 200mV = The full value of internal reference voltage

In this way, the user can easily control the LED strings brightness by controlling the duty cycle of the input PWM signal.

As shown in [Figure 7-1](#), the TPS923621/2 chops up the internal 200mV reference voltage at the duty cycle of the PWM signal. The pulse signal is then filtered by an internal low-pass filter. The output of the filter is connected to the GM amplifier as the reference voltage for the FB pin regulation. Therefore, although a PWM signal is used for brightness dimming, only the LED DC current is modulated, which is often referred as analog dimming. This mechanism eliminates the audible noise which often occurs when the LED current is pulsed in replica of the frequency and duty cycle of PWM control. Unlike other methods which filter the PWM signal for analog dimming, TPS923621/2 regulation voltage is independent of the PWM logic voltage level which often has large variations.

For optimum performance, use the PWM dimming frequency in the range of 10kHz to 200kHz. If the PWM frequency is lower than 10kHz, it is out of the low pass filter's filter range, the FB regulation voltage ripple becomes large, causing large output ripple and may generate audible noise.

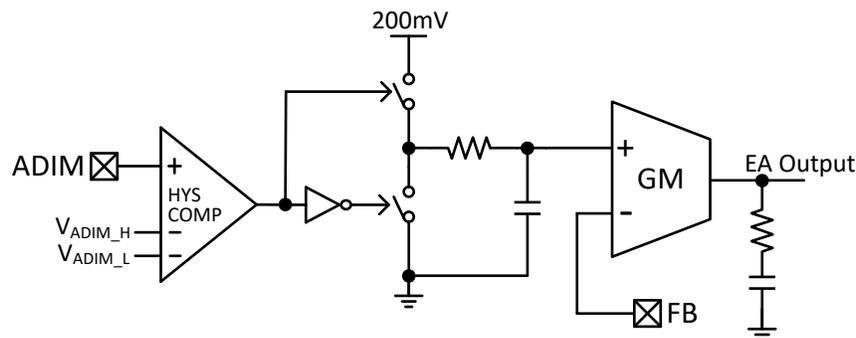


Figure 7-1. FB Voltage Adjusted by PWM Controlled Analog Dimming

7.3.9 Thermal Shutdown

The TPS923621/2 implements thermal shutdown protection to prevent damages due to excessive heat and power dissipation. The thermal shutdown happens when the device junction temperature reaches T_{TSD_R} . When the thermal shutdown is triggered, the TPS923621/2 stops switching until the junction temperature falls below T_{TSD_F} , then the device starts switching again.

7.4 Device Functional Modes

7.4.1 Normal Operation Mode

The TPS923621/2 enters normal operation mode from shutdown mode when the voltage of ADIM pin is higher than the threshold voltage V_{ADIM_H} for a period longer than t_{ADIM_EN} , along with the soft-start process. In normal operation mode, the TPS923621/2 uses peak current mode (PCM) control and operates in forced continuous conduction mode (FCCM) over the entire load range.

7.4.2 Over-Voltage Protection Mode

The TPS923621/2 enters over-voltage protection mode in a VOUT pin over-voltage condition and prevent device from keep turning on and off switching. If the voltage of VOUT pin is detected rising above V_{OVP_R} and then dropping below $V_{OVP_R}-V_{OVP_HYS}$ for 3 times, the TPS923621/2 stays in over-voltage protection mode until the device is reset by one of two ways, which are shutdown and re-enabling device by the ADIM pin or triggering UVLO by the VIN pin. In over-voltage protection mode, the switching stops.

7.4.3 Shutdown Mode

The TPS923621/2 enters shutdown mode from normal operation mode or over-voltage protection mode when the voltage of ADIM pin is lower than the threshold voltage V_{ADIM_L} for a period longer than t_{ADIM_SD} . In shutdown mode, the input supply current for the device is I_{SD} .

8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Application Information

The TPS923621/2 is a boost LED driver which can drive single or parallel LED strings for LCD panel back lighting or general illumination. This section includes a design procedure ([Detailed Design Procedure](#)) to select component values for the TPS923621/2 typical application ([Figure 8-1](#)).

8.2 Typical Application

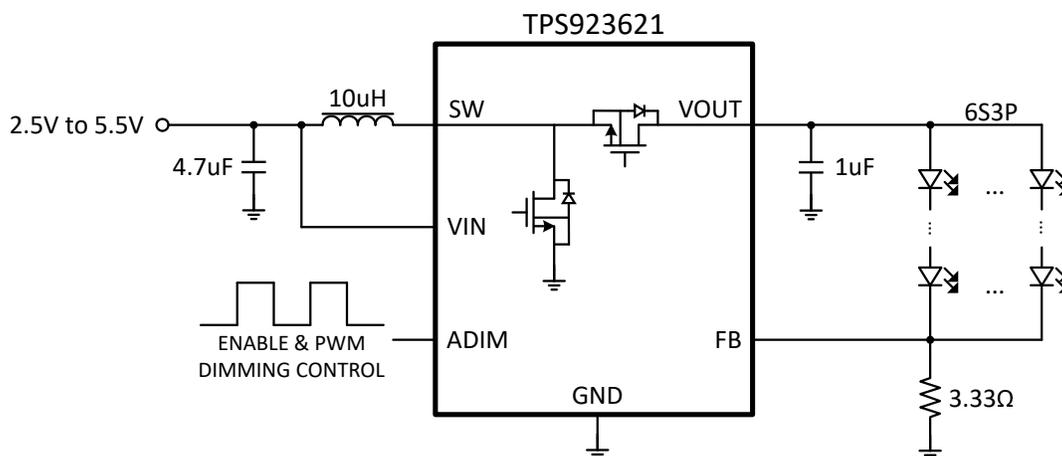


Figure 8-1. TPS923621/2 60mA Total Output Current Reference Design

8.2.1 Design Requirements

For this design example, use the parameters listed in [Table 8-1](#) as the input parameters.

Table 8-1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	2.5V to 5.5V
Output, LED number in a string	6
Output, LED string number	3
Output, LED current per string	20mA

8.2.2 Detailed Design Procedure

8.2.2.1 Inductor Selection

Inductor selection impacts power efficiency, steady-state operation, transient response and loop stability. These factors make inductor selection the most important component in power regulator design. There are three important inductor specifications, inductor value, DC resistance and saturation current. Considering inductor value alone is not enough. The inductor value determines the inductor ripple current. Choose an inductor that can handle the necessary peak current without saturating and optimize light load efficiency when using dimming. In a boost regulator, the input DC current can be calculated as

$$I_{L(DC)} = \frac{V_{OUT} \times I_{OUT}}{V_{IN} \times \eta} \quad (3)$$

where

- V_{OUT} = boost output voltage
- I_{OUT} = boost output current
- V_{IN} = boost input voltage
- η = power conversion efficiency

The inductor current peak to peak ripple can be calculated as

$$\Delta I_{L(P-P)} = \frac{1}{L \times \left(\frac{1}{V_{OUT} - V_{IN}} + \frac{1}{V_{IN}} \right) \times F_S} \quad (4)$$

where

- $\Delta I_{L(PP)}$ = inductor peak-to-peak ripple
- L = inductor value
- F_S = boost switching frequency
- V_{OUT} = boost output voltage
- V_{IN} = boost input voltage

Therefore, the peak current $I_{L(P)}$ seen by the inductor is calculated with

$$I_{L(P)} = I_{L(DC)} + \frac{\Delta I_{L(P-P)}}{2} \quad (5)$$

Also, the valley current $I_{L(V)}$ seen by the inductor is calculated with

$$I_{L(V)} = I_{L(DC)} - \frac{\Delta I_{L(P-P)}}{2} \quad (6)$$

Inductor values can have $\pm 20\%$ tolerance with no current bias. When the inductor current approaches saturation level, inductance can decrease 20% to 35% from the 0A value depending on how the inductor vendor defines saturation current. When using an inductor with a smaller inductance value with relative light load, the inductor current ramps down to below zero before the end of each switching cycle due to forced continuous condition mode (FCCM), which reduces light load efficiency. Large inductance value provides much more output current and higher conversion efficiency. Thus, choose a sufficiently large inductor that maintains a non-negative valley current under light-load conditions helps optimize efficiency.

For these reasons, a 10- μ H inductor is recommended based on input voltage, output voltage and output current condition of this application, to maintain non-negative current in most of load range by PWM controlled analog dimming.

8.2.2.2 Schottky Diode Selection

The TPS923621/2 demands a low forward voltage, high-speed and low capacitance Schottky diode for optimum efficiency. Ensure that the diode average and peak current rating exceeds the average output current and peak

inductor current. In addition, the diode reverse breakdown voltage must exceed the open LED protection voltage. ONSemiconductor NSR0240 is recommended for the TPS923621/2.

8.2.2.3 Output Capacitor Selection

The output capacitor is mainly selected to meet the requirement for the output ripple and loop stability. This ripple voltage is related to capacitance and capacitor equivalent series resistance (ESR). Assuming a capacitor with zero ESR, the minimum capacitance needed for a given ripple can be calculated with

$$C_{OUT} = \frac{(V_{OUT} - V_{IN}) \times I_{OUT}}{V_{OUT} \times F_S \times V_{ripple}} \quad (7)$$

where

- V_{ripple} = peak-to-peak output ripple

The additional part of the ripple caused by ESR is calculated using: $V_{ripple_ESR} = I_{OUT} \times R_{ESR}$

Due to its low ESR, V_{ripple_ESR} could be neglected for ceramic capacitors, a 1 μ F to 4.7 μ F capacitor is recommended for typical application.

8.2.2.4 LED Current Set Resistor

The resistor value to set the LED current (R_{SET}) can be calculated as

$$R_{SET} = \frac{V_{FB}}{I_{OUT}} \quad (8)$$

8.2.2.5 Thermal Considerations

The allowable IC junction temperature must be considered under normal operating conditions. This restriction limits the power dissipation of the TPS923621/2. The allowable power dissipation for the device can be determined by

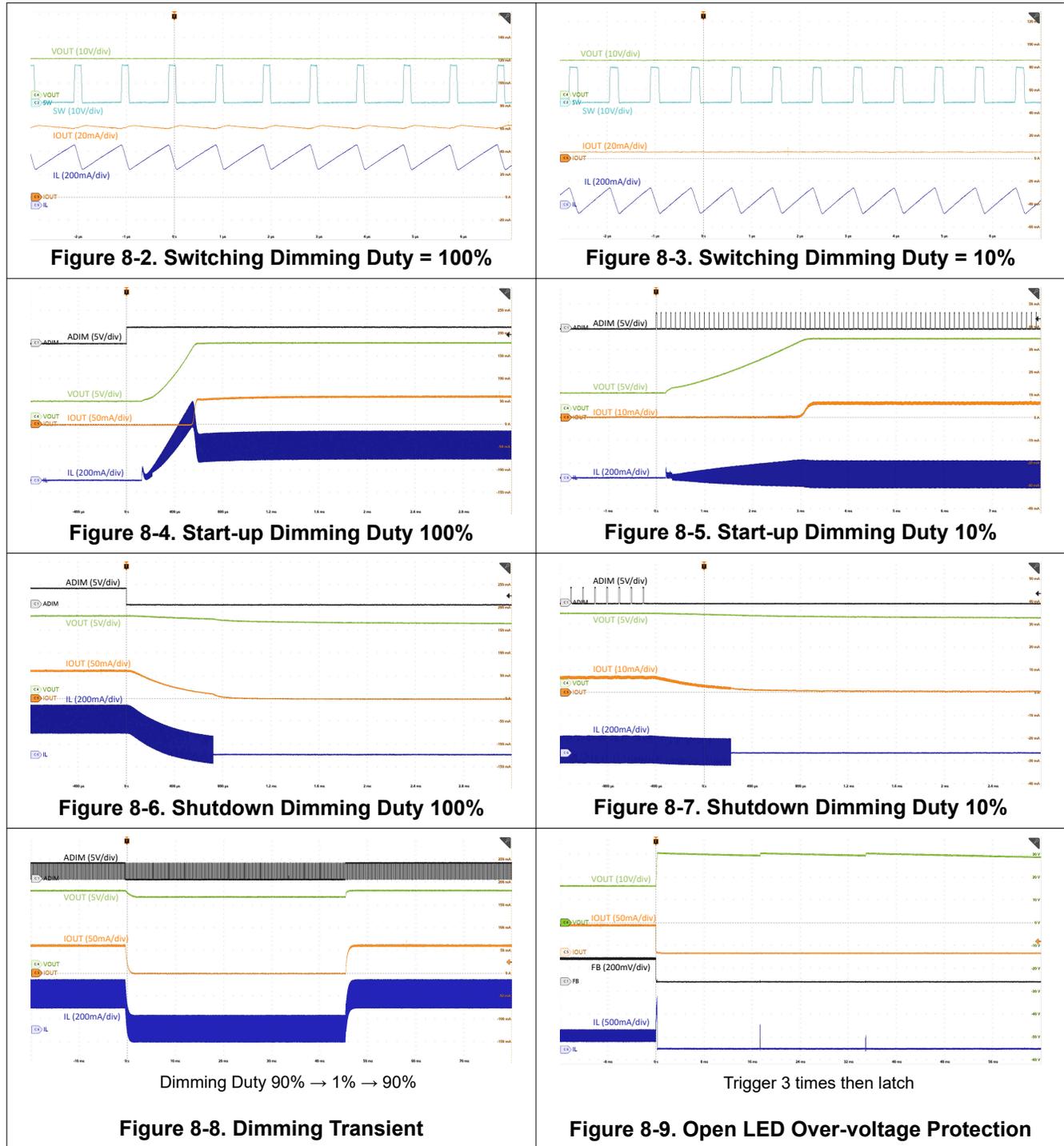
$$P_D = \frac{T_J - T_A}{R_{\theta JA}} \quad (9)$$

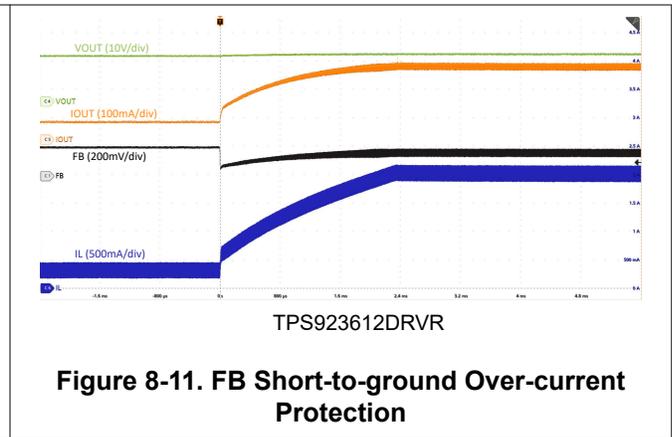
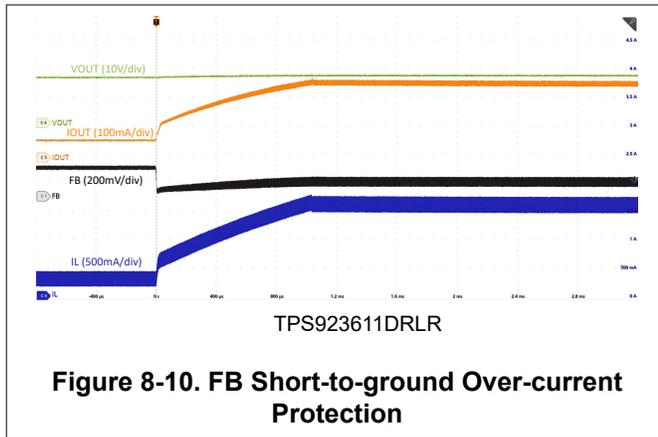
where

- T_J is allowable junction temperature given in recommended operating conditions
- T_A is the ambient temperature for the application
- $R_{\theta JA}$ is the thermal resistance junction-to-ambient given in Power Dissipation Table

8.2.3 Application Curves

Typical application condition is as in Section 8.2, $V_{IN} = 3.6V$, $R_{SET} = 3.33\Omega$, $L = 10\mu H$, $C_{OUT} = 1\mu F$, 6 LEDs in serial in each string and total 3 strings in parallel (unless otherwise specified).





8.3 Power Supply Recommendations

The device is designed to operate from an input voltage supply range between 2.5V and 5.5V. This input supply must be well regulated. If the input supply is located more than a few inches from the TPS923621/2 devices, additional bulk capacitance may be required in addition to the ceramic bypass capacitors.

8.4 Layout

8.4.1 Layout Guidelines

As for all switching power supplies, especially those high frequency and high current ones, layout is an important design step. If layout is not carefully done, the regulator can suffer from instability as well as noise problems. Therefore, use wide and short traces for high current paths. Please follow the layout guidelines below.

1. The output capacitor C_{OUT} must be put close to VOUT pin. Having the ground of C_{OUT} close to the GND pin (GND copper pour) is also beneficial because there is large ground return current flowing between them. This minimizes the switching noise at output.
2. FB resistor must be put close to FB pin and GND pin (GND copper pour). This benefits the output current accuracy.
3. The SW pin carries high current with fast rising and falling edge; therefore, the connection between the SW pin to the inductor must be kept as short and wide as possible.
4. The input capacitor C_{IN} must be close to VIN pin and GND pin to reduce the input ripple seen by the device. If possible, choose a capacitance of higher value.
5. When laying out signal ground, TI recommends using short traces separated from power ground traces and connecting them together at a single point close to the GND pin.

8.4.2 Layout Example

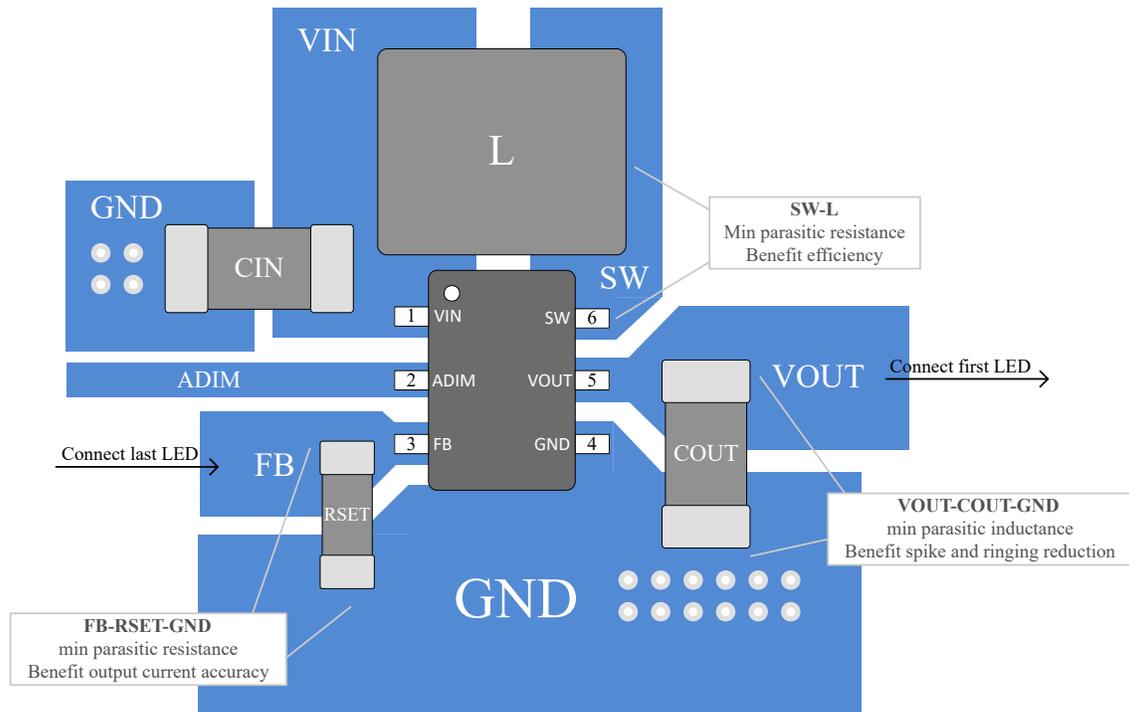


Figure 8-12. TPS923621 SOT563 Layout

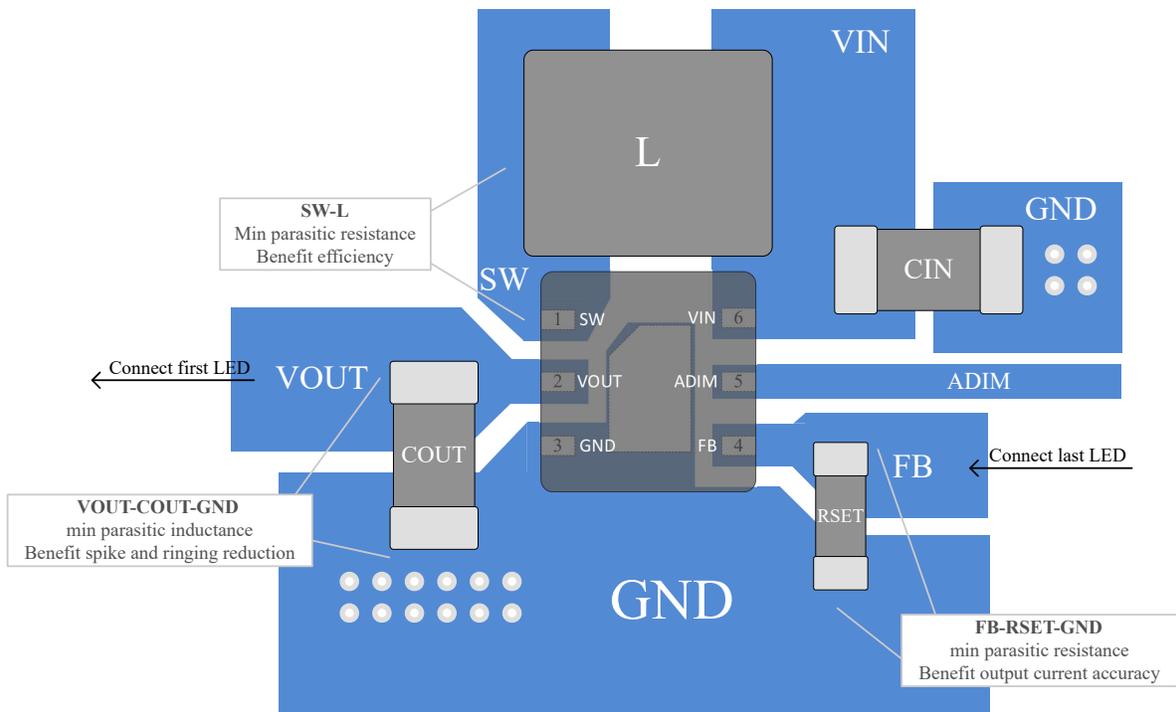


Figure 8-13. TPS923622 WSON Layout

9 Device and Documentation Support

9.1 Device Support

9.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.3 Support Resources

[TI E2E™ support forums](#) are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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9.4 Trademarks

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9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

DATE	REVISION	NOTES
October 2025	*	Initial Release

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS923621DRLR	Active	Production	SOT-5X3 (DRL) 6	4000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	T621
TPS923622DRV	Active	Production	WSON (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	T622

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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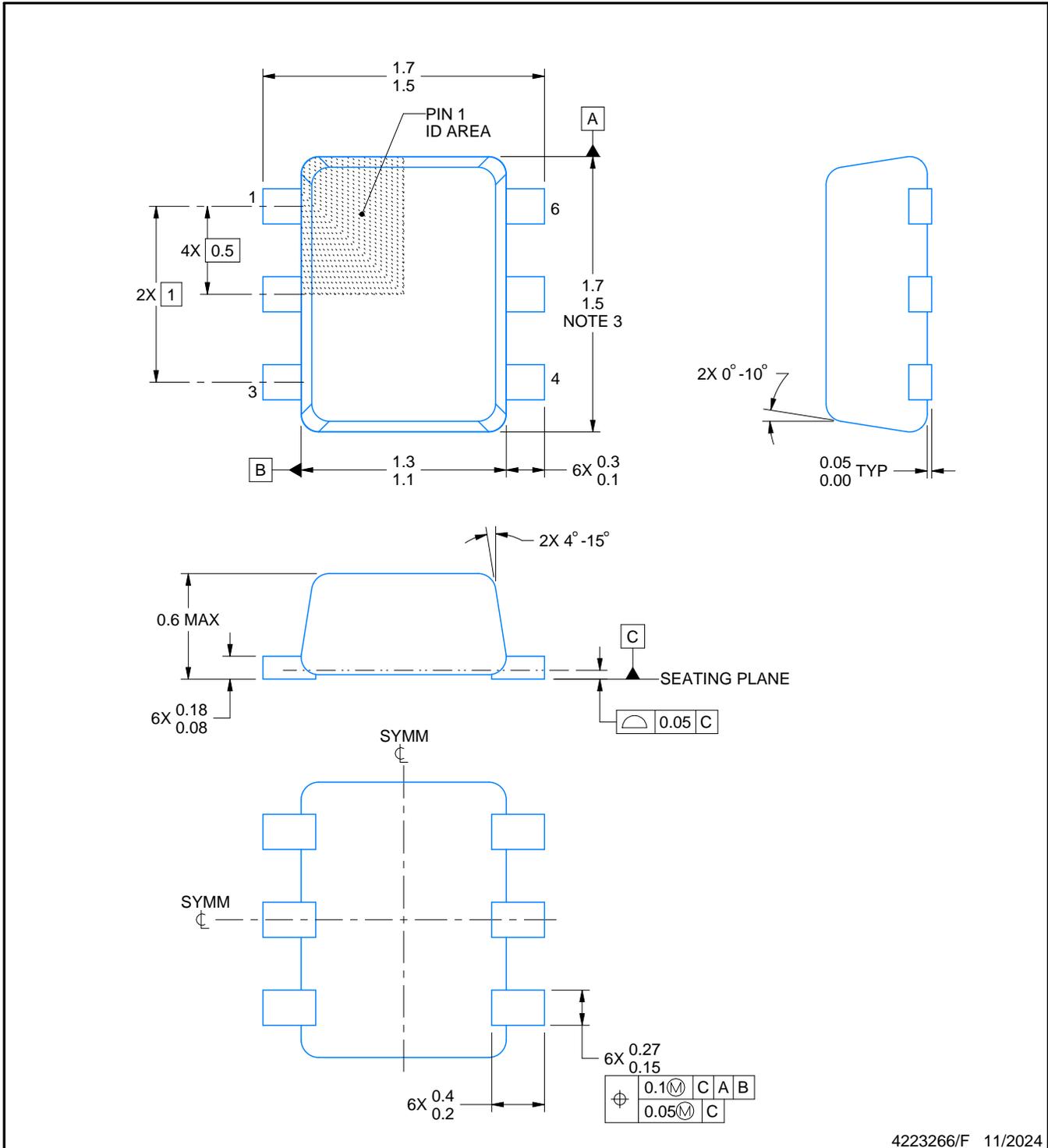
DRL0006A



PACKAGE OUTLINE

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



4223266/F 11/2024

NOTES:

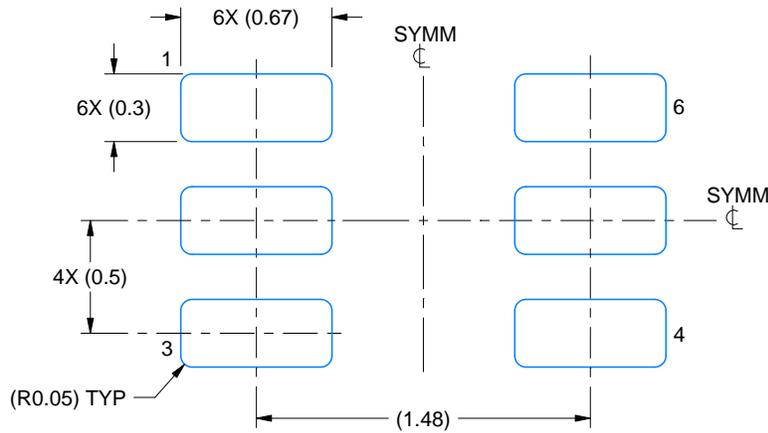
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-293 Variation UAAD

EXAMPLE BOARD LAYOUT

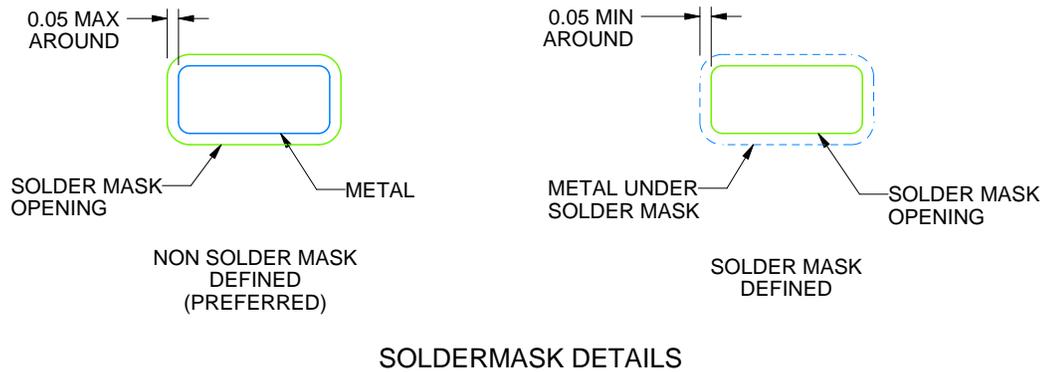
DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



LAND PATTERN EXAMPLE
SCALE:30X



SOLDERMASK DETAILS

4223266/F 11/2024

NOTES: (continued)

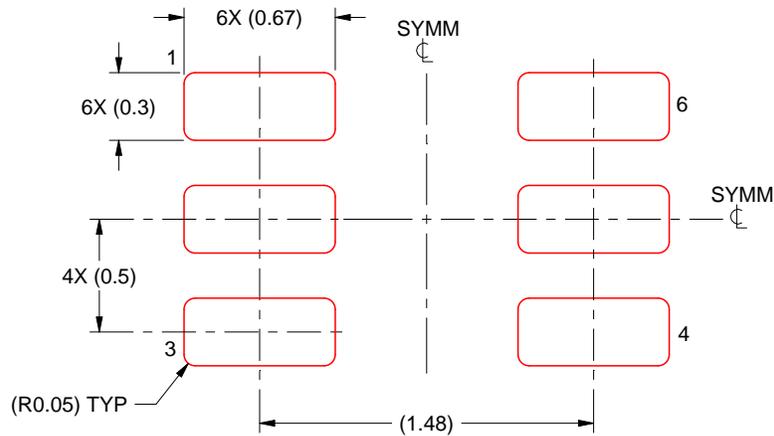
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.

EXAMPLE STENCIL DESIGN

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:30X

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NOTES: (continued)

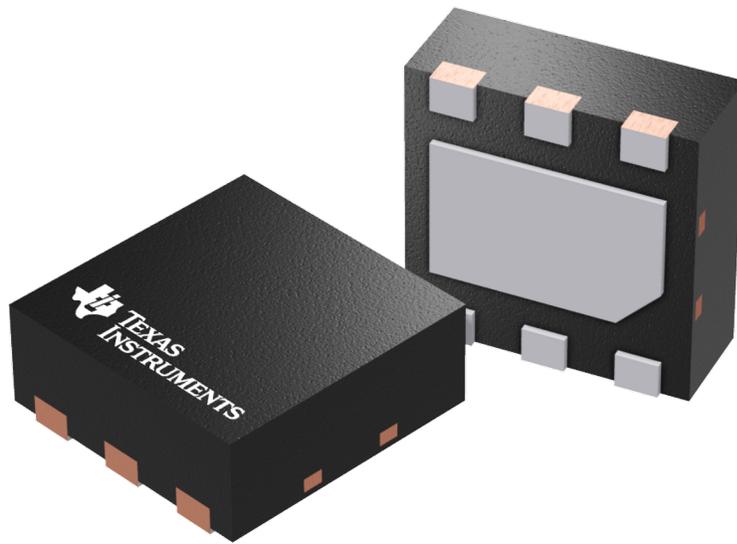
8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

GENERIC PACKAGE VIEW

DRV 6

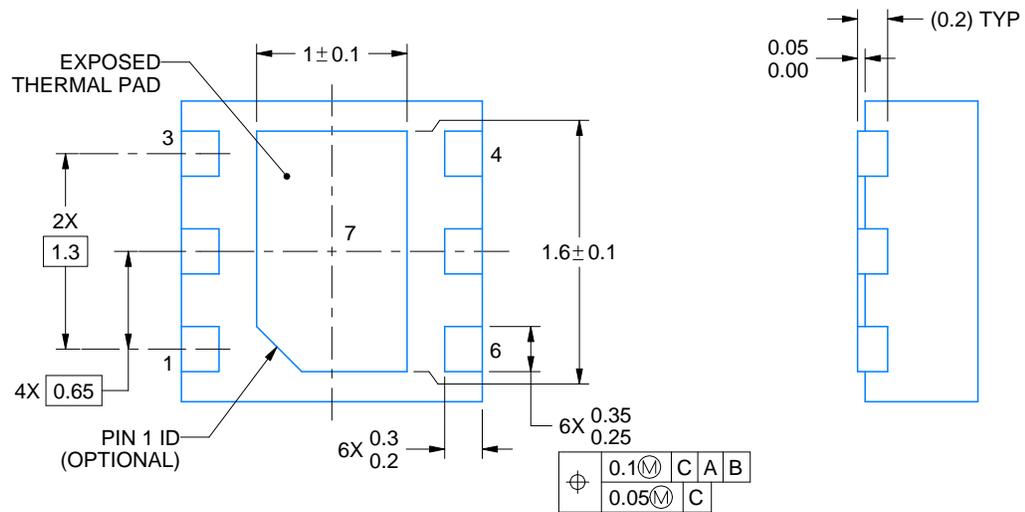
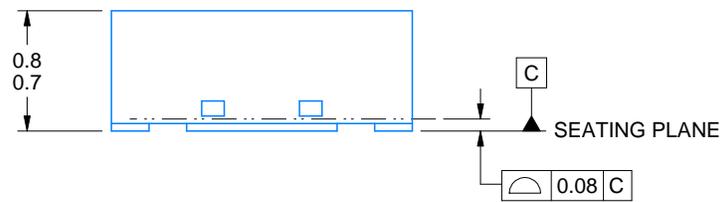
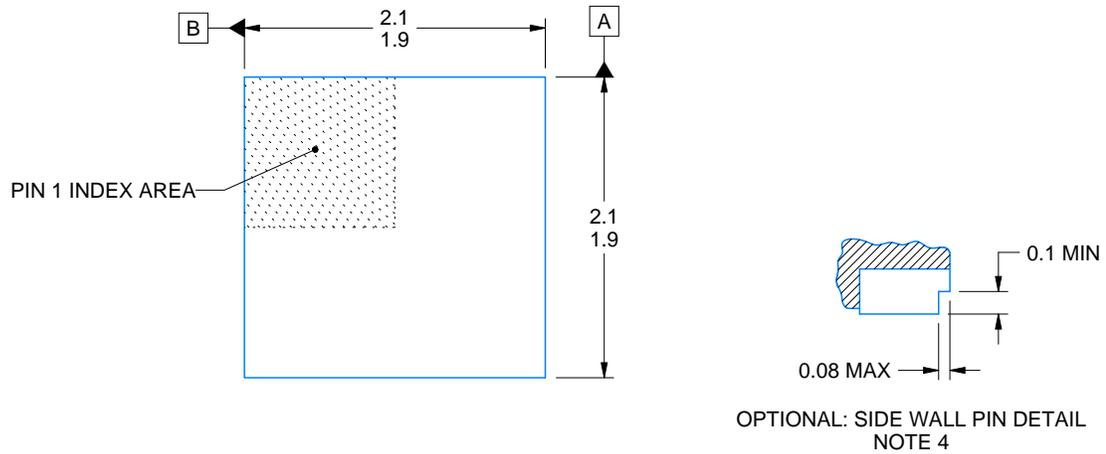
WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4206925/F



4222173/C 11/2025

NOTES:

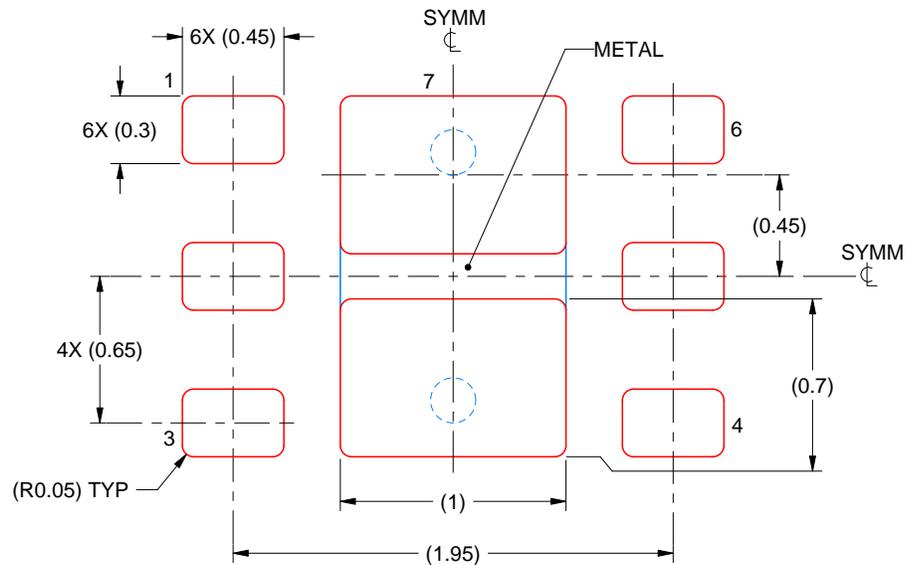
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
4. Minimum 0.1 mm solder wetting on pin side wall. Available for wettable flank version only.

EXAMPLE STENCIL DESIGN

DRV0006A

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4222173/C 11/2025

NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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